# Rectifier diodes ultrafast

#### **BYR29 series**

#### FEATURES

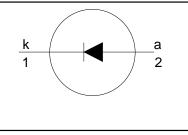
- Low forward volt drop
- Fast switching
- Soft recovery characteristic
- Reverse surge capability
- High thermal cycling performance
- Low thermal resistance

#### **GENERAL DESCRIPTION**

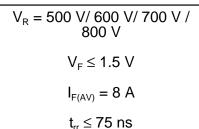
Ultra-fast, epitaxial rectifier diodes intended for use as output rectifiers in high frequency switched mode power supplies.

The BYR29 series is supplied in the conventional leaded SOD59 (TO220AC) package.

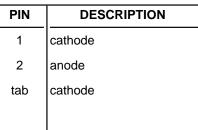
## SYMBOL



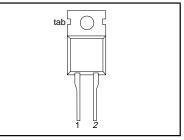
#### QUICK REFERENCE DATA



#### PINNING



#### SOD59 (TO220AC)



#### LIMITING VALUES

Limiting values in accordance with the Absolute Maximum System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.			UNIT	
V <sub>RRM</sub>	Peak repetitive reverse voltage	BYR29	-	<b>-500</b> 500	<b>-600</b> 600	<b>-700</b> 700	<b>-800</b> 800	V
V <sub>RWM</sub> V <sub>R</sub>	Crest working reverse voltage Continuous reverse voltage		-	500 500	600 600	700 700	800 800	V V
I <sub>F(AV)</sub>	Average forward current <sup>1</sup>	square wave; δ = 0.5; T <sub>mb</sub> ≤ 115 °C	-		٤	8		A
I <sub>FRM</sub>	Repetitive peak forward current	$t = 25 \ \mu s; \ \delta = 0.5;$ $T_{mb} \le 115 \ ^{\circ}C$	-		1	6		A
I <sub>FSM</sub>	Non-repetitive peak forward current	t = 10 ms t = 8.3 ms sinusoidal; with reapplied V <sub>RRM(max)</sub>	-			60 66		A A
T <sub>stg</sub> T <sub>j</sub>	Storage temperature Operating junction temperature	······································	-40 -			50 50		°C °C

#### THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
R <sub>th j-mb</sub>	Thermal resistance junction to mounting base		-	-	2.5	K/W
R <sub>th j-a</sub>	Thermal resistance junction to ambient	in free air.	-	60	-	K/W

<sup>1</sup> Neglecting switching and reverse current losses

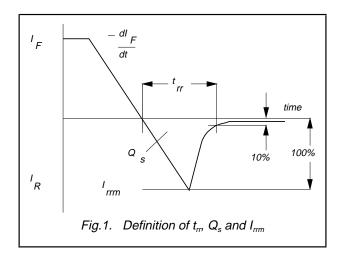
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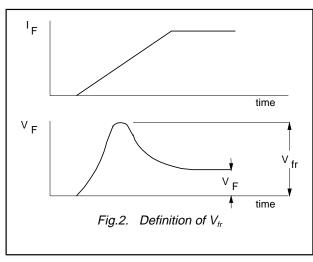
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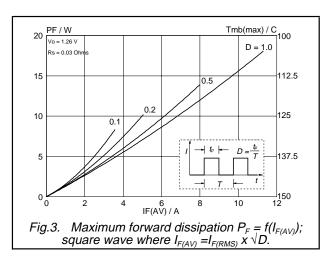
#### **ELECTRICAL CHARACTERISTICS**

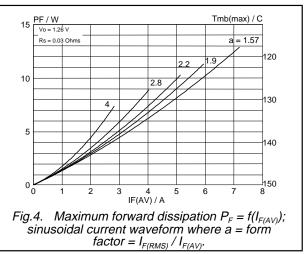
 $T_i = 25$  °C unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V <sub>F</sub>	Forward voltage	I <sub>F</sub> = 8 A; T <sub>j</sub> = 150°C	-	1.07	1.50	V
		$I_{\rm F} = 20  {\rm A}^{-1}$	-	1.75	1.95	V
I <sub>R</sub>	Reverse current	$\dot{V}_{R} = V_{RRM}$	-	1.0	10	μA
		$V_{\rm P} = V_{\rm DDM}$ ; T = 100 °C	-	0.1	0.2	mΑ
Q <sub>s</sub>	Reverse recovery charge	$ I_{\rm F} = 2 \text{ A to } V_{\rm R}^{\prime} \ge 30 \text{ V};$	-	150	200	nC
Ū		$dI_{F}/dt = 20 A/\mu s$				
t <sub>rr</sub>	Reverse recovery time	$I_F = 1 \text{ A to } V_R \ge 30 \text{ V};$	-	60	75	ns
		$dI_{F}/dt = 100 \text{ A}/\mu \text{s}$				
l <sup>rrm</sup>	Peak reverse recovery current	$I_{\rm F} = 10 \text{ A to } V_{\rm R} \ge 30 \text{ V};$	-	-	6	Α
		$dI_{r}/dt = 50 A/us; T_{r} = 100 °C$				
V <sub>fr</sub>	Forward recovery voltage	$I_{F} = 10 \text{ A}; dI_{F}/dt = 10 \text{ A}/\mu \text{s}$	-	5.0	-	V





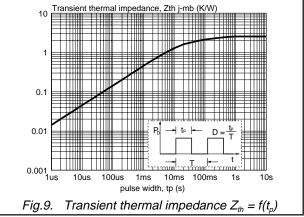




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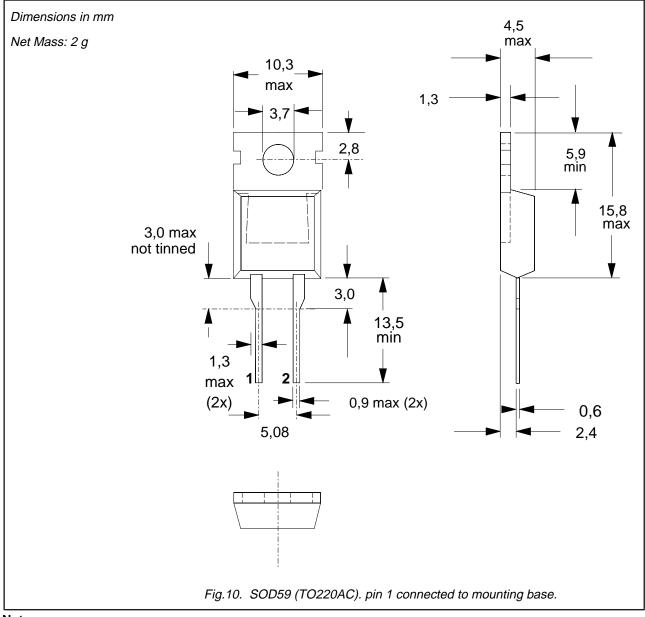
#### trr / ns IF / A 1000 30 Tj = 25 C IF=10 A Tj = 150 C 25 1A-100 20 15 max typ 10 10 \_\_\_\_\_\_Tj = 25 C \_\_\_\_\_Tj = 100 C 5 0 L. 0 1 100 0.5 1.5 2 2.5 3 10 dIF/dt (A/us) 1 VF/V Fig.7. Typical and maximum forward characteristic $I_F = f(V_F)$ ; parameter $T_j$ Fig.5. Maximum $t_{rr}$ at $T_i = 25^{\circ}C$ and $100^{\circ}C$ . 1000 Qs / nC Irrm / A 10 IF=10A IF = 10A 1 IF=1A 100 0.1 -Tj = 25 C -Tj = 100 C 0.01 10 10 -dIF/dt (A/us) 100 1 1.0 10 -dIF/dt (A/us) 100 Fig.6. Maximum $I_{rrm}$ at $T_j = 25^{\circ}C$ and $100^{\circ}C$ . Fig.8. Maximum $Q_s$ at $T_i = 25^{\circ}C$ 10



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#### **MECHANICAL DATA**



#### Notes

Refer to mounting instructions for TO220 envelopes.
Epoxy meets UL94 V0 at 1/8".

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#### DEFINITIONS

Data sheet status				
Objective specification	Dbjective specification This data sheet contains target or goal specifications for product development.			
Preliminary specification	reliminary specification This data sheet contains preliminary data; supplementary data may be published late			
Product specification	uct specification This data sheet contains final product specifications.			
Limiting values				
or more of the limiting val operation of the device at	in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one lues may cause permanent damage to the device. These are stress ratings only and t these or at any other conditions above those given in the Characteristics sections of applied. Exposure to limiting values for extended periods may affect device reliability.			
Where application information is given, it is advisory and does not form part of the specification.				
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